V20PWM12C

Vishay General Semiconductor

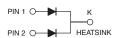
High Current Density Surface-Mount TMBS[®] (Trench MOS Barrier Schottky) Rectifier

Ultra Low $V_F = 0.55$ V at $I_F = 5$ A



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SlimDPAK (TO-252AE)



LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS | | | | |
|-----------------------------------------|---------------------|--|--|--|
| I _{F(AV)} | 2 x 10 A | | | |
| V _{RRM} | 120 V | | | |
| I _{FSM} | 150 A | | | |
| V_F at I_F = 10 A (T_A = 125 °C) | 0.65 V | | | |
| T _J max. | 175 °C | | | |
| Package | SlimDPAK (TO-252AE) | | | |
| Circuit configuration | Common cathode | | | |

FEATURES

- Very low profile typical height of 1.3 mm
- Trench MOS Schottky technology
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in low voltage high frequency DC/DC converters, freewheeling diodes, and polarity protection applications.

MECHANICAL DATA

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

| MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | |
|---------------------------------------------------------------------------------------------|------------------|-----------------------------------|-------------|------|
| PARAMETER | | SYMBOL | V20PWM12C | UNIT |
| Device marking code | | | V20PWM12C | |
| Maximum repetitive peak reverse voltage | V _{RRM} | 120 | V | |
| Maximum average forward rectified current (Fig. 1) | per device | . (1) | 20 | А |
| | per diode | I _{F(AV)} ⁽¹⁾ | 10 | А |
| Peak forward surge current 8.3 ms single half sine-was superimposed on rated load per diode | I _{FSM} | 150 | А | |
| Operating junction temperature range | | T _J ⁽²⁾ | -40 to +175 | °C |
| Storage temperature range | | T _{STG} | -55 to +175 | °C |

Notes

⁽¹⁾ With infinite heatsink

⁽²⁾ The heat generated must be less than the thermal conductivity from junction to ambient: $dP_D/dT_1 < 1/R_{B,IA}$

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RoHS COMPLIANT

HALOGEN FREE

V20PWM12C



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| ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | | | |
|-----------------------------------------------------------------------------------|------------------------|---------------------------|-------------------------------|------|------|------|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT |
| Instantaneous forward voltage per diode | I _F = 5.0 A | T _A = 25 °C | V _E (1) | 0.65 | - | V |
| | I _F = 10 A | | | 0.84 | 0.92 | |
| | I _F = 5.0 A | - T _A = 125 °C | | 0.55 | - | |
| | I _F = 10 A | | | 0.65 | 0.73 | |
| Reverse current per diode | V _B = 90 V | T _A = 25 °C | I _R ⁽²⁾ | 0.01 | - | mA |
| | $v_{\rm R} = 90 v$ | T _A = 125 °C | | 2 | - | |
| | $V_{\rm D} = 120 V$ | T _A = 25 °C | | - | 0.3 | |
| | | T _A = 125 °C | | 4 | 10 | |
| Typical junction capacitance | 4.0 V, 1 MHz | | CJ | 840 | - | pF |

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: pulse width \leq 5 ms

| THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | |
|--------------------------------------------------------------------------------|---------------------------------|-----------|------|--|
| PARAMETER | SYMBOL | V20PWM12C | UNIT | |
| Typical thermal resistance | R _{0JA} (1)(2) | 55 | °C/W | |
| | R _{0JM} ⁽³⁾ | 1.8 | 0/10 | |

Notes

⁽¹⁾ The heat generated must be less than thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$

 $^{(2)}$ Free air, mounted on recommended copper pad area; thermal resistance $R_{\theta JA}$ - junction to ambient

 $^{(3)}$ Mounted on infinite heat sink; thermal resistance $R_{\theta JM}$ - junction-to-mount

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|-----------------|------------------------|---------------|------------------------------------|--|--|
| PREFERRED P/N | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | |
| V20PWM12C-M3/I | 0.20 | I | 4500 | 13" diameter plastic tape and reel | | |
| V20PWM12CHM3/I (1) | 0.20 | I | 4500 | 13" diameter plastic tape and reel | | |

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

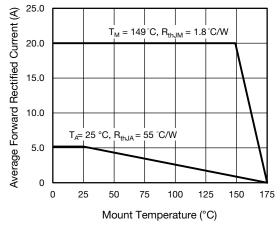


Fig. 1 - Maximum Forward Current Derating Curve

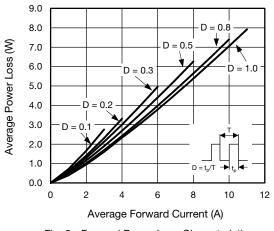


Fig. 2 - Forward Power Loss Characteristics

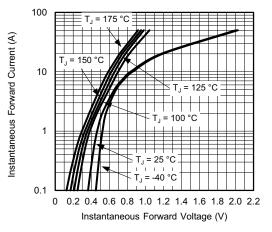


Fig. 3 - Typical Instantaneous Forward Characteristics

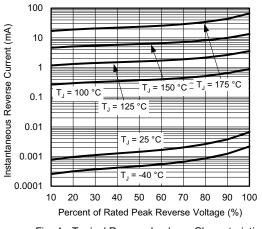
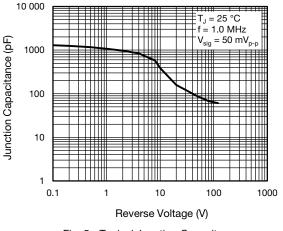


Fig. 4 - Typical Reverse Leakage Characteristics





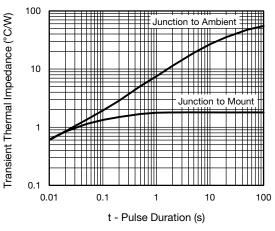


Fig. 6 - Typical Transient Thermal Impedance

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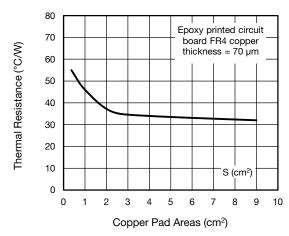
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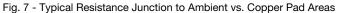
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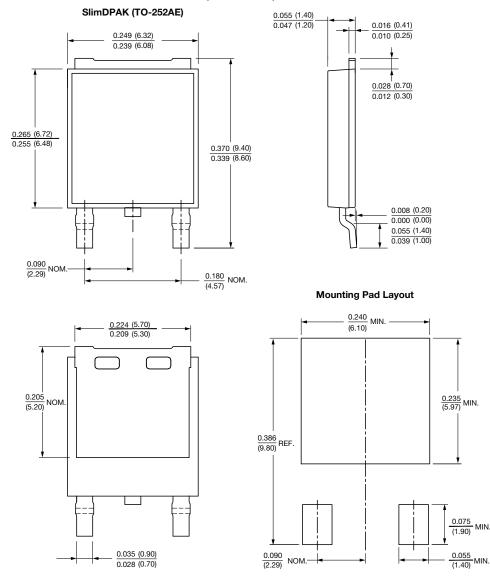


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